

# Silicon Carbide (SiC) Schottky Diode – EliteSiC, 6 A, 650 V, D2, DPAK

# FFSD0665B-F085

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

#### **Features**

- Max Junction Temperature 175°C
- Avalanche Rated 24.5 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### **Applications**

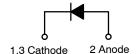
- Automotive HEV-EV Onboard Chargers
- Automotive HEV-EV DC-DC Converters

#### MAXIMUM RATINGS (T, I = 25°C unless otherwise noted)

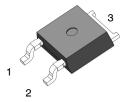
Parameter		Symbol	Value	Unit
Peak Repetitive Reverse Voltage		$V_{RRM}$	650	V
Single Pulse Avalanche Energy ( $T_J = 25^{\circ}C$ , $I_{L(pk)} = 9.9$ A, L = 0.5 mH, V = 50 V)		E <sub>AS</sub>	24.5	mJ
Continuous Rectified Forward	T <sub>C</sub> < 154	l <sub>F</sub>	6.0	Α
Current	T <sub>C</sub> < 135		9.1	
Non-Repetitive Peak Forward Surge Current	T <sub>C</sub> = 25°C, t <sub>P</sub> = 10 μs	I <sub>FM</sub>	493	Α
	$T_{C} = 150^{\circ}C,$ $t_{P} = 10 \ \mu s$		442	
Non-Repetitive Forward Surge Current (Half-Sine Pulse)	$T_C = 25^{\circ}C$ $t_P = 8.3 \text{ ms}$	I <sub>FSM</sub>	28	Α
Power Dissipation	T <sub>C</sub> = 25°C	P <sub>tot</sub>	75	W
	T <sub>C</sub> = 150°C		12.5	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

V <sub>RRM</sub>	l <sub>F</sub>		
650 V	6.0 A		

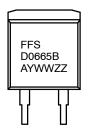


**Schottky Diode** 



DPAK CASE 369AS

# **MARKING DIAGRAM**



FFSD0665B

= Specific Device Code

л У = Assembly Location

Y WW

= Work Week

= Year

ZZ

= Assembly Lot Code

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

# FFSD0665B-F085

### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{ heta JC}$	Thermal Resistance, Junction-to-Case	2.0	°C/W

### **ELECTRICAL CHARACTERISTICS**

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
N CHARAC	TERISTICS					
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 6.0 A, T <sub>J</sub> = 25°C	-	1.38	1.7	V
		I <sub>F</sub> = 6.0 A, T <sub>J</sub> = 125°C	-	1.53	2.0	1
		I <sub>F</sub> = 6.0 A, T <sub>J</sub> = 175°C	-	1.67	2.4	1
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 650 V, T <sub>J</sub> = 25°C	-	0.5	40	μΑ
		V <sub>R</sub> = 650 V, T <sub>J</sub> = 125°C	-	1.0	80	1
		V <sub>R</sub> = 650 V, T <sub>J</sub> = 175°C	-	2.0	160	
IARGES, C	APACITANCES & GATE RES	ISTANCE				
$Q_C$	Total Capacitive Charge	V <sub>C</sub> = 400 V	-	16	-	nC
C <sub>tot</sub>	7	V <sub>R</sub> = 1 V, f = 100 kHz	-	259	_	pF
		V <sub>R</sub> = 200 V, f = 100 kHz	-	29	-	1
		V <sub>B</sub> = 400 V, f = 100 kHz	-	22	-	1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

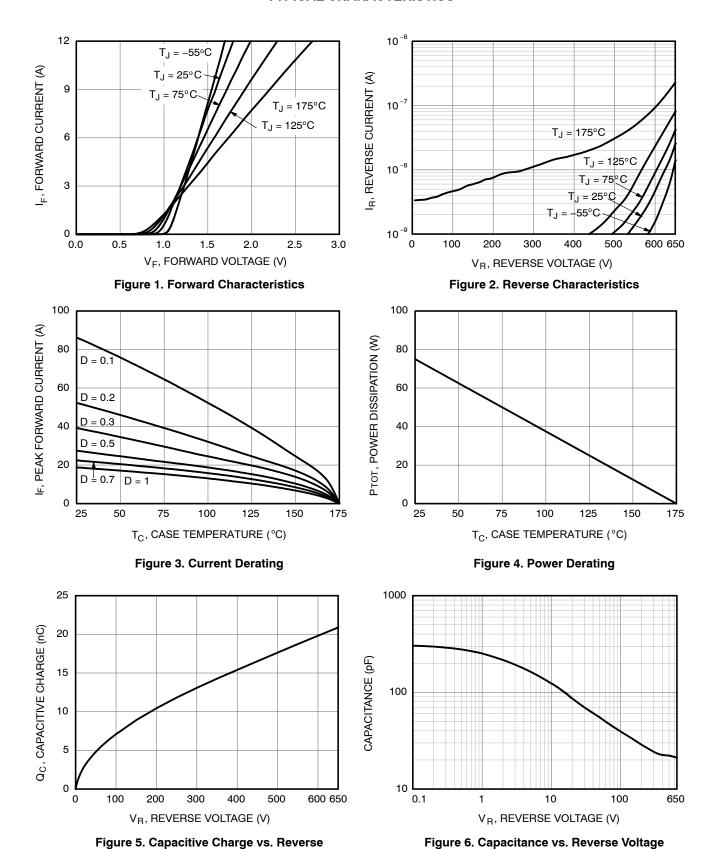
# PART MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method <sup>†</sup>	Reel Size	Tape Width	Quantity
FFSD0665B-F085	FFSD0665B	DPAK	Tape & Reel	330 mm	16 mm	2500 units

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

# FFSD0665B-F085

# **TYPICAL CHARACTERISTICS**



Voltage

# FFSD0665B-F085

# **TYPICAL CHARACTERISTICS**

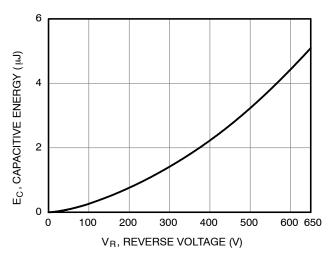


Figure 7. Capacitance Stored Energy

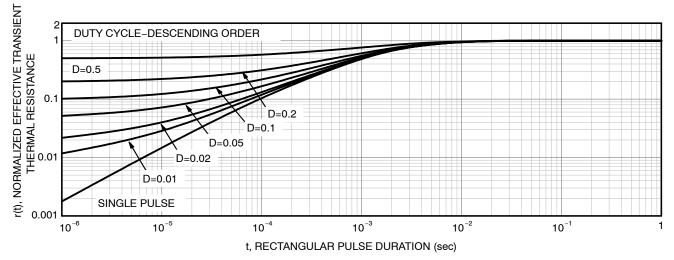


Figure 8. Junction-to-Case Transient Thermal Response





### DPAK3 6.10x6.54x2.29, 4.57P CASE 369AS **ISSUE B**

**DATE 20 DEC 2023** 

- NOTES: UNLESS OTHERWISE SPECIFIED

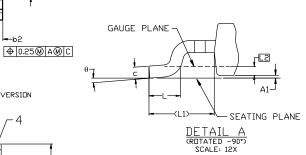
  A) THIS PACKAGE CONFORMS TO JEDEC, TO-252, ISSUE F, VARIATION AA.

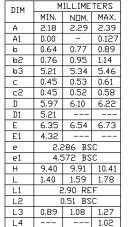
  B) ALL DIMENSIONS ARE IN MILLIMETERS.

  C) DIMENSIONING AND TOLERANCING PER

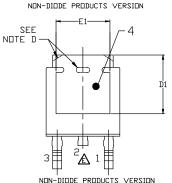
  - D>

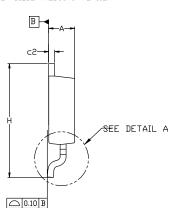
- A
- F)
- DIMENSIONING AND TOLERANCING PER
  ASME Y14.5M-2018.
  SUPPLIER DEPENDENT MOLD LOCKING HOLES OR CHAMFERED
  CORNERS OR EDGE PROTRUSION.
  FOR DIGDE PRODUCTS, L4 IS 0.25 MM MAX PLASTIC BODY
  STUB WITHOUT CENTER LEAD.
  DIMENSIONS ARE EXCLUSIVE OF BURRS,
  MOLD FLASH AND TIE BAR EXTRUSIONS.
  LAND PATTERN RECOMMENDATION IS BASED ON IPC7351A STD
  T0228P991X239-3N.

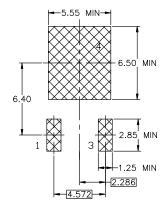




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#### LAND PATTERN RECOMMENDATION

\*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

## **GENERIC MARKING DIAGRAM\***

10°

XXXXXX XXXXXX **AYWWZZ** 

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXXX = Specific Device Code

= Assembly Location Α

Υ = Year

WW = Work Week

77 = Assembly Lot Code

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